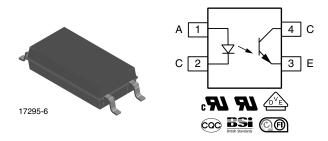


# Optocoupler, Phototransistor Output, Low Input Current, 4 Pin LSOP, Long Creepage Mini-Flat Package



#### **DESCRIPTION**

The VOL618A has a GaAs infrared emitting diode emitter, which is optically coupled to a silicon planar phototransistor detector, and is incorporated in a 4 pin LSOP wide body package.

It features a high current transfer ratio, low coupling capacitance, and high isolation voltage.

The coupling device is designed for signal transmission between two electrically separated circuits.

#### **FEATURES**

- Low profile package
- High collector emitter voltage, V<sub>CEO</sub> = 80 V
- Isolation test voltage, 5000 V<sub>RMS</sub>
- Isolation voltage V<sub>IORM</sub> = 1050 V<sub>peak</sub>
- · Low coupling capacitance
- High common mode transient immunity
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912





COMPLIANT
HALOGEN
FREE
GREEN
(5-2008)

#### **APPLICATIONS**

- Telecom
- · Industrial controls
- · Battery powered equipment
- · Office machines
- · Programmable controllers

#### **AGENCY APPROVALS**

(All parts are certified under base model VOL618A)

- UL1577, file no. E76222
- cUL CSA 22.2 bulletin 5A, double protection
- DIN EN 60747-5-5 (VDE 0884-5), available with option 1
- BSI: EN 60065:2002, EN 60950-1:2006
- FIMKO EN60950-1
- CQC: GB8898-2011, GB4943.1-2011

ORDERING INFORMATION						
V O L 6 1 8 PART NUMBER		0 0 1 T  KAGE OPTION TAPE AND REEL	LSOP-5			
AGENCY CERTIFIED/PACKAGE	CTR (%)					
AGENCY CENTIFIED/PACKAGE	1 mA					
UL, cUL, BSI, FIMKO, CQC	50 to 600	63 to 125	100 to 200			
4 pin LSOP, mini-flat, long creepage	VOL618AT	VOL618A-2T	VOL618A-3T			
UL, cUL, BSI, FIMKO, CQC, VDE (option 1)	50 to 600	63 to 125	100 to 200			
4 pin LSOP, mini-flat, long creepage	_	VOL618A-2X001T	VOL618A-3X001T			

<b>ABSOLUTE MAXIMUM RATINGS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
INPUT	·					
Reverse voltage		V <sub>R</sub>	6	V		
Power dissipation		P <sub>diss</sub>	100	mW		
Forward current		I <sub>F</sub>	60	mA		
Forward surge current	t <sub>p</sub> < 10 μs	I <sub>FSM</sub>	1.5	Α		
Junction temperature		T <sub>j</sub>	125	°C		
OUTPUT	·					
Collector emitter voltage		$V_{CEO}$	80	V		
Emitter collector voltage		V <sub>ECO</sub>	7	V		
Collector current		I <sub>C</sub>	50	mA		
Collector current	$t_p/T = 0.5, t_p < 10 \text{ ms}$	Ic	100	mA		
Power dissipation		P <sub>diss</sub>	150	mW		
Junction temperature		Tj	125	°C		
COUPLER						
Total power dissipation		P <sub>tot</sub>	250	mW		
Storage temperature range		T <sub>stg</sub>	-55 to +125	°C		
Ambient temperature range		T <sub>amb</sub>	-55 to +110	°C		
Soldering temperature (1)	≤ 10 s	T <sub>sld</sub>	260	°C		

#### **Notes**

(1) Refer to reflow profile for soldering conditions for surface mounted devices.

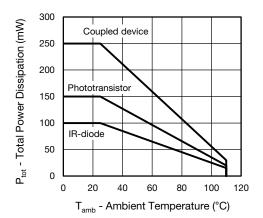


Fig. 1 - Total Power Dissipation vs. Ambient Temperature

PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT					•	•	
Forward voltage	$I_F = 5 \text{ mA}$		$V_{F}$	-	1.16	1.5	V
Capacitance	$V_R = 0 V, f = 1 MHz$		Co	-	45	-	pF
Reverse current	V <sub>R</sub> = 6 V		I <sub>R</sub>	-	-	100	μA
OUTPUT							
Collector emitter leakage current	$V_{CE} = 10 \text{ V}, I_F = 0 \text{ A}$		I <sub>CEO</sub>	-	10	200	nA
Collector emitter capacitance	V <sub>CE</sub> = 5 V, f = 1 MHz		C <sub>CE</sub>	-	7	-	pF
COUPLER							
Oallanda a sailla a a la sailla a	$I_C = 0.32 \text{ mA}, I_F = 1 \text{ mA}$	VOL618A-2	V <sub>CEsat</sub>	-	0.25	0.4	V
Collector emitter saturation voltage	$I_C = 0.5 \text{ mA}, I_F = 1 \text{ mA}$	VOL618A-3	V <sub>CEsat</sub>	-	0.25	0.4	V
	$I_C = 0.8 \text{ mA}, I_F = 1 \text{ mA}$	VOL618A-4	V <sub>CEsat</sub>	-	0.25	0.4	V
Coupling capacitance	f = 1 MHz		C <sub>C</sub>	-	0.25		pF

#### Not

 Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
maximum ratings for extended periods of the time can adversely affect reliability.



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CURRENT TRANSFER RATIO (T <sub>amb</sub> = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
I <sub>C</sub> /I <sub>F</sub>	I <sub>F</sub> = 1 mA, V <sub>CE</sub> = 5 V	VOL618A	CTR	50	-	600	%
		VOL618A-2	CTR	63	-	125	%
		VOL618A-3	CTR	100	-	200	%

<b>SWITCHING CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Turn on time	$V_{CC}$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$	t <sub>on</sub>	-	6	-	μs
Rise time	$V_{CC}$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$	t <sub>r</sub>	-	3.5	-	μs
Turn off time	$V_{CC}$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$	t <sub>off</sub>	-	5.5	-	μs
Fall time	$V_{CC}$ = 5 V, $I_C$ = 2 mA, $R_L$ = 100 $\Omega$	t <sub>f</sub>	-	5	-	μs

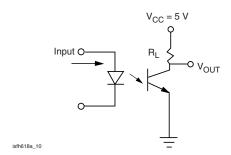


Fig. 2 - Test Circuit

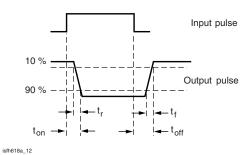


Fig. 3 - Test Circuit and Waveforms

SAFETY AND INSULATION RATINGS						
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT		
Partial discharge test voltage - routine test	100 %, t <sub>test</sub> = 1 s	$V_{pd}$	2	kV <sub>peak</sub>		
Partial discharge test voltage -	$t_{Tr} = 60 \text{ s}, t_{test} = 10 \text{ s},$	V <sub>IOTM</sub>	8	kV <sub>peak</sub>		
lot test (sample test)	(see figure 4)	$V_{pd}$	1.68	$kV_{peak}$		
Isolation test voltage between emitter and detector	t = 1 min	V <sub>ISO</sub>	5000	V <sub>RMS</sub>		
Insulation voltage		V <sub>IORM</sub>	1050	V <sub>peak</sub>		
	$V_{IO} = 500 V_{DC}, T_{amb} = 25 °C$	R <sub>IO</sub>	10 <sup>12</sup>	Ω		
Insulation resistance	$V_{IO} = 500 V_{DC}, T_{amb} = 100 °C$	R <sub>IO</sub>	10 <sup>11</sup>	Ω		
incolation resistance	V <sub>IO</sub> = 500 V <sub>DC</sub> , T <sub>amb</sub> = 150 °C (construction test only)	R <sub>IO</sub>	10 <sup>9</sup>	Ω		
Safety rating - maximum input current		I <sub>si</sub>	130	mA		
Safety rating - maximum power dissipation		P <sub>SO</sub>	265	mW		
Rated impulse voltage		V <sub>IOTM</sub>	8	kV		
Safety rating - maximum ambient temperature		T <sub>si</sub>	150	°C		
Comparative tracking index		CTI	275	mm		
Clearance distance			8	mm		
Creepage distance			8	mm		
Insulation distance (internal)			0.4	mm		

### Note

• According to DIN EN 60747-5-5 (VDE 0884), § 7.4.3.8.2, (see figure 4). This optocoupler is suitable for safe electrical isolation only within the safety ratings. Compliance with the safety ratings shall be ensured by means of suitable protective circuits.



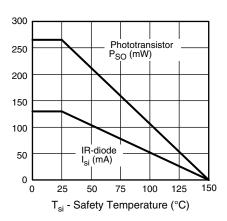


Fig. 4 - Derating Diagram

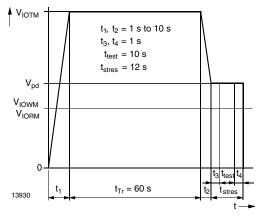


Fig. 5 - Test Pulse Diagram for Sample Test according to DIN EN 60747-5-5

### TYPICAL CHARACTERISTICS (T<sub>amb</sub> = 25 °C, unless otherwise specified)

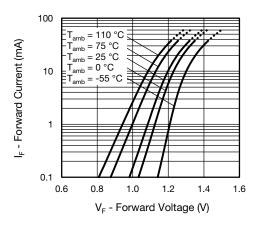


Fig. 6 - Forward Voltage vs. Forward Current

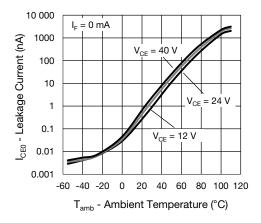


Fig. 8 - Collector Emitter Current vs. Ambient Temperature

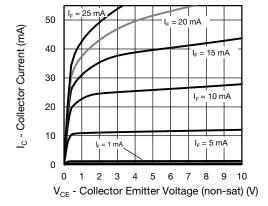


Fig. 7 - Collector Current vs. Collector Emitter Voltage (non-saturated)

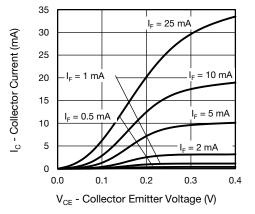


Fig. 9 - Collector Current vs. Collector Emitter Voltage (saturated)

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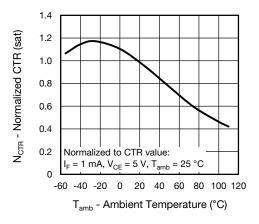


Fig. 10 - Normalized Current Transfer Ratio vs. Ambient Temperature (saturated)

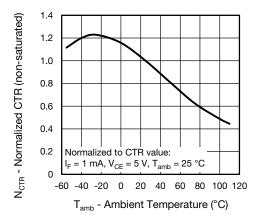


Fig. 11 - Normalized Current Transfer Ratio vs. Ambient Temperature (non-saturated)

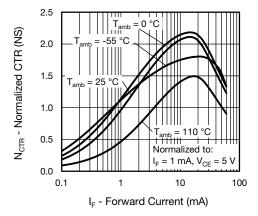


Fig. 12 - Current Transfer Ratio vs. Forward Current (saturated) Normalized to 1 mA at 25 °C

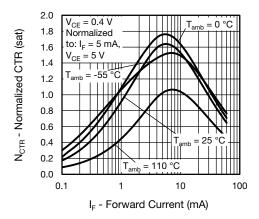


Fig. 13 - Current Transfer Ratio vs. Forward Current (non-saturated) Normalized to 1 mA at 25 °C

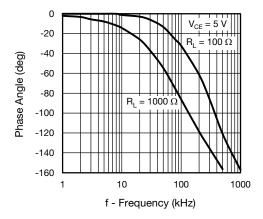


Fig. 14 - f<sub>CTR</sub> vs. Phase Angle

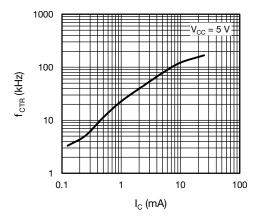


Fig. 15 - Frequency (-3 dB) vs. Collector Current



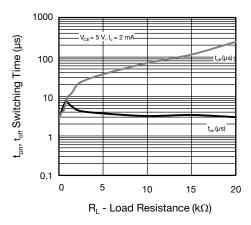


Fig. 16 - Switching Time vs. Load Resistance

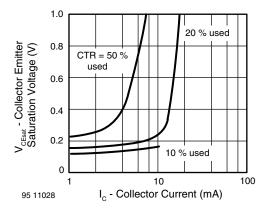


Fig. 17 - Collector Emitter Saturation Voltage vs. Collector Current

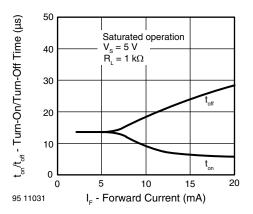


Fig. 18 - Turn-On/Turn-Off Time vs. Forward Current

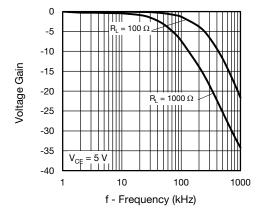
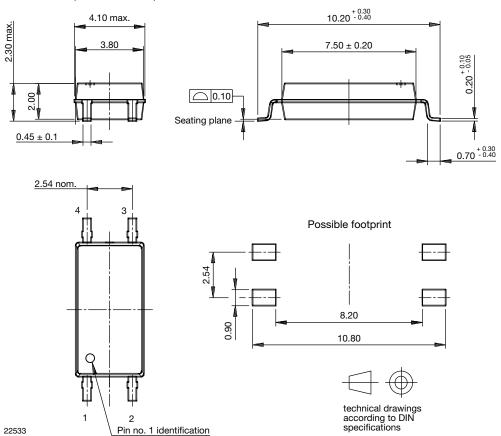


Fig. 19 - Voltage Gain vs. Cut-off Frequency

### **PACKAGE DIMENSIONS** (in millimeters)



### PACKAGE MARKING (example of VOL618A-3X001T)



#### **Notes**

- Only option 1 is reflected in the package marking with the characters "X1".
- Tape and reel suffix (T) is not part of the package marking.

### TAPE AND REEL DIMENSIONS (in millimeters)

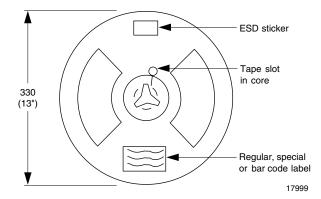


Fig. 20 - Reel Dimensions (3000 units per reel)

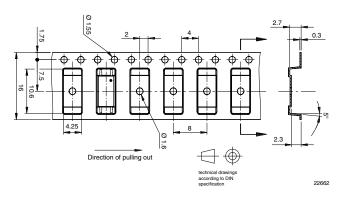


Fig. 21 - Tape Dimensions



### **SOLDER PROFILE**

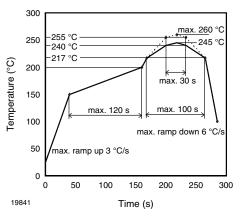


Fig. 22 - Lead (Pb)-free Reflow Solder Profile according to J-STD-020

### HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions:  $T_{amb}$  < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



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